



RADSAGA

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ESR9

Predictive tools and "Radiation Hardening By Design" (RHBD) for SEU and SET in digital circuits

RADSAGA Training Workshop – March 2018

Ygor Q. de Aguiar aguiar@ies.univ-montp2.fr









Who am I?

"Carioca da Gema" and Gaúcho by heart...

- BSc. in Automation Engineering, 2015
 - 1-year scholarship in Budapest, Hungary
- MSc. in Microelectronics, 2017
 - Radiation and Variability effects in FinFET based circuits

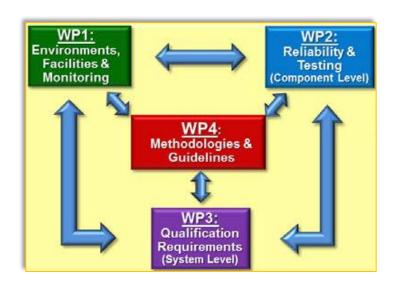








Technical Work Packages (WPs)



WP1:

ESR1, ESR2, ESR3, ESR4, ESR5

WP2:

ESR6, ESR7, ESR8, ESR9, ESR10, ESR11

WP3:

ESR12, ESR13, ESR14

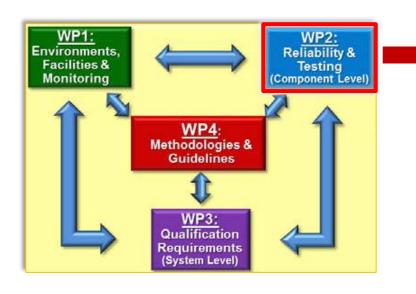
WP4:

ESR15





Technical Work Packages (WPs)



State-of-the-art electronic components

- Time-based signal processing circuit
- CMOS imager
- Power device technologies

Synergetic and Coupled Effects

- Stochastic and cumulative radiation effects
- Aging effects

Predictive Tools and RHBD techniques

- Soft Errors (SET and SEU)
- Single Event Latchup





Expected Results for ESR9

- A simulation chain including various environments building on existing methodologies and tools;
- 2) Evaluation of the SEU cross section for the defined technologies;
- 3) Study, analysis and grouping of SET features for selected CMOS transistor technologies;
- 4) Determination of design rules to minimize the effect of radiations.





SEE Prediction

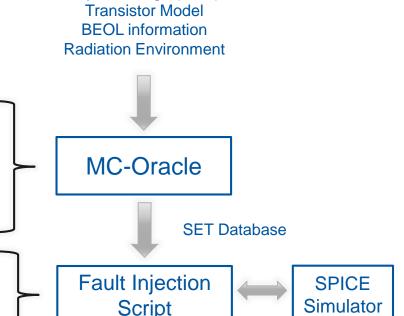
Particle Interaction Simulation:

Particle Transport
Charge Generation and Collection

-> Drift-Diffusion Model

Electrical Simulation:

Layout Effects (Parasitics Extraction)
Circuit Response Effects



Layout Design (GDS)





SEE Prediction

Collaborative Work



ESR4:

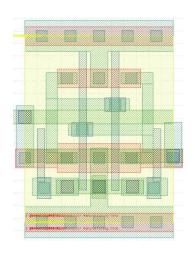
Comparative analysis of the FLUKA and MC-Oracle tools

ESR5:

Predict the SEU cross-section of the SRAM memory cell

ESR8:

 Address the aging mechanisms to the modeling of the prediction tool







Secondments

Aix-Marseille University, Marseille, France

- Prof. Jean-Luc Autran
- May to July of 2018 (2 months)

KU Leuven University, Leuven, Belgium

- Prof. Paul Leroux
- 2 months in 2019

CERN, Geneve, Swirtzerland

- Dr. Rúben Garcia Alia
- 1 month in 2019











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Thank you!

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Current Works

Analysis of the Charge Sharing effect in the SET sensitivity of bulk 45nm standard-cell layouts under heavy ions

Submitted to ESREF2018

The Impact of Complex-logic cell layout on the SET response under heavy ions

To be submitted to RADECS2018





Gantt Chart

	2.2017	1.2018	2.2018	1.2019	2.2019	1.2020
Literature Review						
Simulation tools						
Circuit Design						
Methodology Development						
Radiation Testing						
Publication						
Secondments						
Thesis Writing						



